

Improved Quad CMOS Analog Switches

DESCRIPTION

The DG201B, DG202B analog switches are highly improved versions of the industry-standard DG201A, DG202. These devices are fabricated in Vishay Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control, computer peripherals, etc. An improved charge injection compensation design minimizes switching transients. The DG201B and DG202B can handle up to ± 22 V input signals, and have an improved continuous current rating of 30 mA. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply voltages in the off condition.

The DG201B is a normally closed switch and the DG202B is a normally open switch. (see Truth Table.)

FEATURES

- ± 22 V supply voltage rating
- TTL and CMOS compatible logic
- Low on-resistance - $R_{DS(on)}$: 45 Ω
- Low leakage - $I_{D(on)}$: 20 pA
- Single supply operation possible
- Extended temperature range
- Fast switching - t_{ON} : 120 ns
- Low glitching - Q: 1 pC
- Compliant to RoHS Directive 2002/95/EC



RoHS*
COMPLIANT

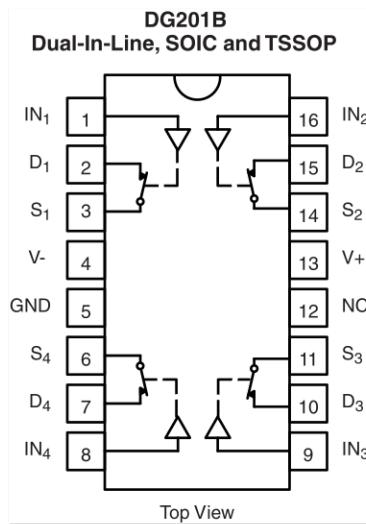
BENEFITS

- Wide analog signal range
- Simple logic interface
- Higher accuracy
- Minimum transients
- Reduced power consumption
- Superior to DG201A, DG202
- Space savings (TSSOP)

APPLICATIONS

- Industrial instrumentation
- Test equipment
- Communications systems
- Disk drives
- Computer peripherals
- Portable instruments
- Sample-and-hold circuits

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	DG201B	DG202B
0	ON	OFF
1	OFF	ON

Logic "0" ≤ 0.8 V

Logic "1" ≥ 2.4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply



ORDERING INFORMATION

Temp. Range	Package	Part Number
- 55 °C to 125 °C	16-pin CerDIP	DG201BAK
		DG202BAK
	16-pin Plastic DIP	DG201BDJ
		DG201BDJ-E3
		DG202BDJ
		DG202BDJ-E3
	16-pin narrow SOIC	DG201BDY
		DG201BDY-E3
		DG201BDY-T1
		DG201BDY-T1-E3
	16-pin TSSOP	DG202BDY
		DG202BDY-E3
		DG202BDY-T1
		DG202BDY-T1-E3
- 40 °C to 85 °C	16-pin TSSOP	DG201BDQ
		DG201BDQ-E3
		DG201BDQ-T1
		DG201BDQ-T1-E3
		DG202BDQ
		DG202BDQ-E3
		DG202BDQ-T1
		DG202BDQ-T1-E3

ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit
Voltages Referenced, V+ to V-	44	V
GND	25	
Digital Inputs ^a , V _S , V _D	(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current (Any terminal)	30	mA
Peak Current S or D (Pulsed at 1 ms, 10 % duty cycle max.)	100	
Storage Temperature	(AK, DK suffix)	°C
	(DJ, DY, DQ suffix)	
Power Dissipation (Package) ^b	16-pin plastic DIP ^c	mW
	16-pin narrow SOIC and TSSOP ^d	
	16-pin CerDIP ^e	
	LCC-20 ^f	

Notes:

- a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.5 mW/°C above 75 °C.
- d. Derate 7.6 mW/°C above 75 °C.
- e. Derate 12 mW/°C above 75 °C.
- f. Derate 10 mW/°C above 75 °C.

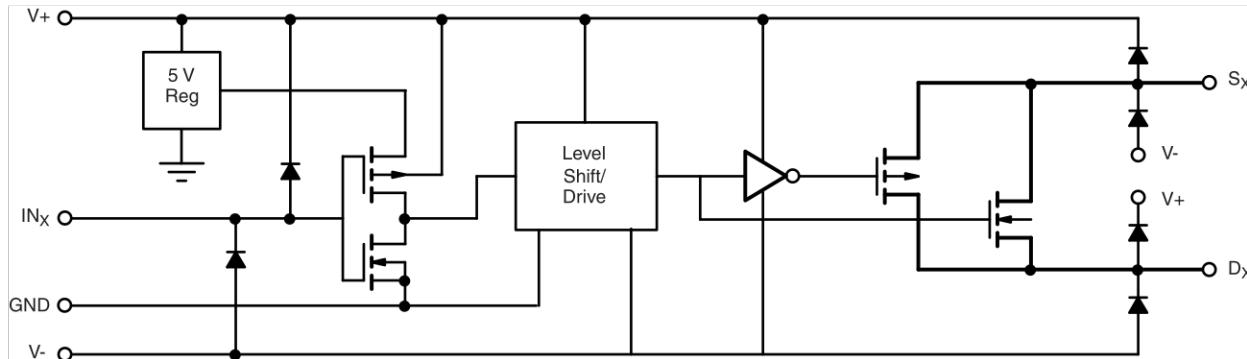
SCHEMATIC DIAGRAM (typical channel)


Figure 1.

SPECIFICATIONS^a								
Parameter	Symbol	Test Conditions Unless Specified $V_+ = 15 \text{ V}$, $V_- = -15 \text{ V}$ $V_{IN} = 2.4 \text{ V}$, 0.8 V^f	Temp. ^b	A Suffix		D Suffix		Unit
				Typ. ^c	Min. ^d	Max. ^d	Min. ^d	
Analog Switch								
Analog Signal Range ^e	V_{ANALOG}		Full		-15	15	-15	15
Drain-Source On-Resistance	$R_{DS(on)}$	$V_D = \pm 10 \text{ V}$, $I_S = 1 \text{ mA}$	Room	45		85		85
$R_{DS(on)}$ Match	$\Delta R_{DS(on)}$		Room	2		100		100
Source Off Leakage Current	$I_{S(off)}$	$V_S = \pm 14 \text{ V}$, $V_D = \pm 14 \text{ V}$	Room	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5
Drain Off Leakage Current	$I_{D(off)}$	$V_D = \pm 14 \text{ V}$, $V_S = \pm 14 \text{ V}$	Room	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5
Drain On Leakage Current	$I_{D(on)}$	$V_S = V_D = \pm 14 \text{ V}$	Room	± 0.02	-0.5 -40	0.5 40	-0.5 -10	0.5 10
Digital Control								
Input Voltage High	V_{INH}		Full		2.4		2.4	
Input Voltage Low	V_{INL}		Full			0.8		0.8
Input Current	I_{INH} or I_{INL}	V_{INH} or V_{INL}	Full		-1	1	-1	1
Input Capacitance	C_{IN}		Room	5				pF
Dynamic Characteristics								
Turn-On Time	t_{ON}	$V_S = 2 \text{ V}$ see switching time test circuit	Room	120		300		300
Turn-Off Time	t_{OFF}		Room	65		200		200
Charge Injection	Q	$C_L = 1000 \text{ pF}$, $V_g = 0 \text{ V}$ $R_g = 0 \Omega$	Room	1				pC
Source-Off Capacitance	$C_{S(off)}$	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$	Room	5				
Drain-Off Capacitance	$C_{D(off)}$		Room	5				pF
Channel On Capacitance	$C_{D(on)}$	$V_D = V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$	Room	16				
Off Isolation	OIRR	$C_L = 15 \text{ pF}$, $R_L = 50 \Omega$ $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 100 \text{ kHz}$	Room	90				
Channel-to-Channel Crosstalk	X_{TALK}		Room	95				dB
Power Supply								
Positive Supply Current	I_+	$V_{IN} = 0$ or 5 V	Room			50 100		50 100
Negative Supply Current	I_-		Room		-1 -5		-1 -5	
Power Supply Range for Continuous Operation	V_{OP}		Full		± 4.5	± 22	± 4.5	± 22
Document Number: 70037 S11-0800-Rev. J, 25-Apr-11								
This document is subject to change without notice. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000								
www.vishay.com								
3								

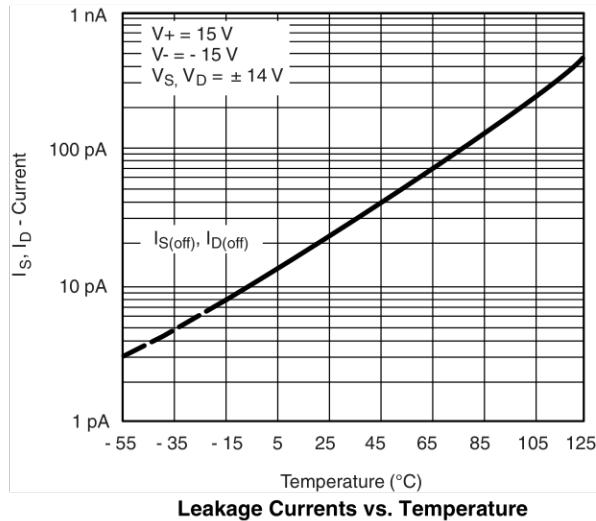
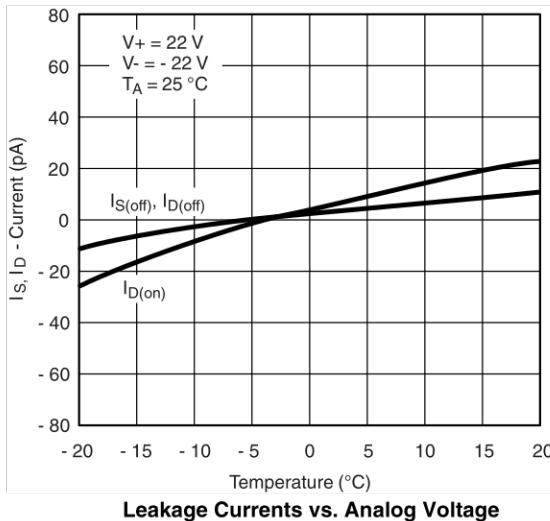
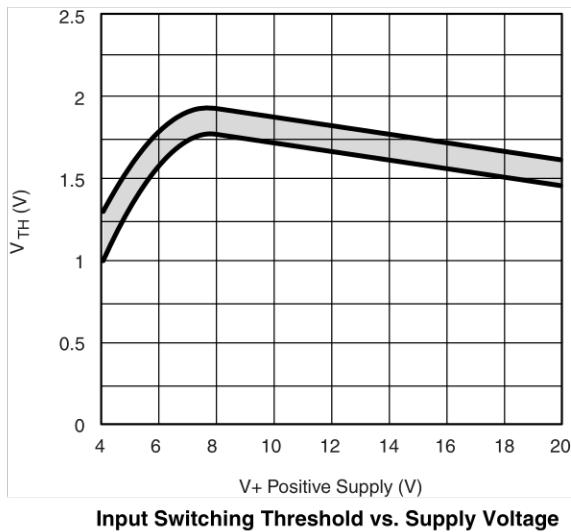
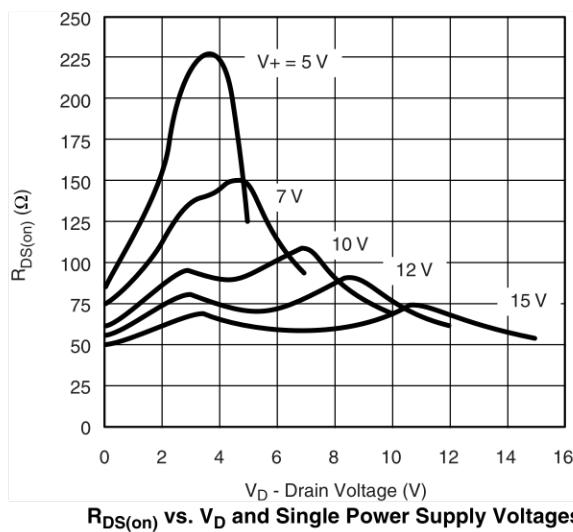
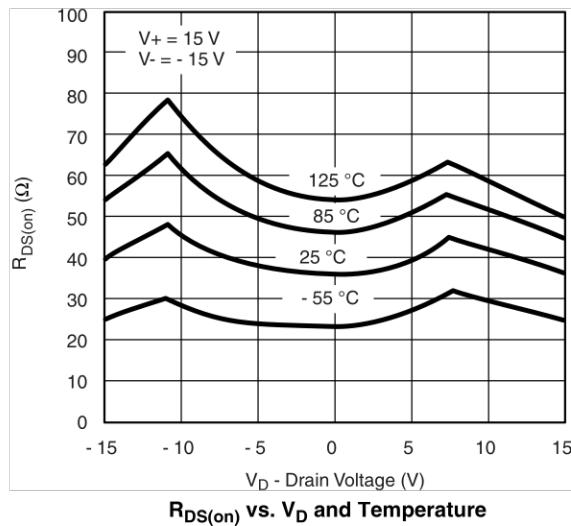
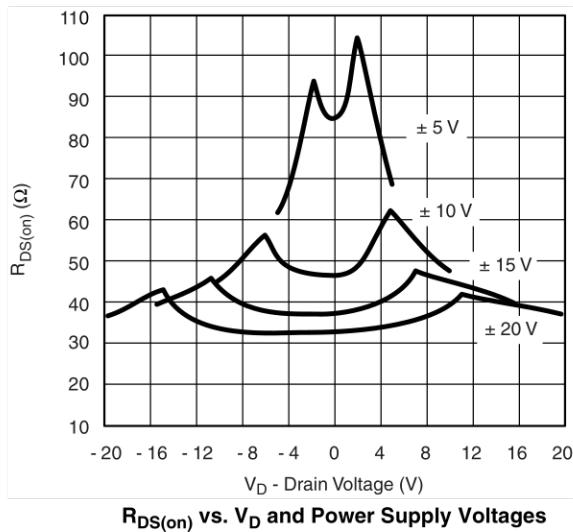
SPECIFICATIONS (for Single Supply)^a

Parameter	Symbol	Test Conditions Unless Specified $V_+ = 12 \text{ V}$, $V_- = 0 \text{ V}$ $V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V_{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_D = 3 \text{ V}, 8 \text{ V}$, $I_S = 1 \text{ mA}$	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics									
Turn-On Time	t_{ON}	$V_S = 8 \text{ V}$ see switching time test circuit	Room	120		300		300	ns
Turn-Off Time	t_{OFF}		Room	60		200		200	
Charge Injection	Q	$C_L = 1 \text{ nF}$, $V_{gen} = 6 \text{ V}$ $R_{gen} = 0 \Omega$	Room	4					pC
Power Supply									
Positive Supply Current	I_+	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full			50 100		50 100	μA
Negative Supply Current	I_-		Room Full		- 1 - 5		- 1 - 5		
Power Supply Range for Continuous Operation	V_{OP}		Full		+ 4.5	+ 25	+ 4.5	+ 25	V

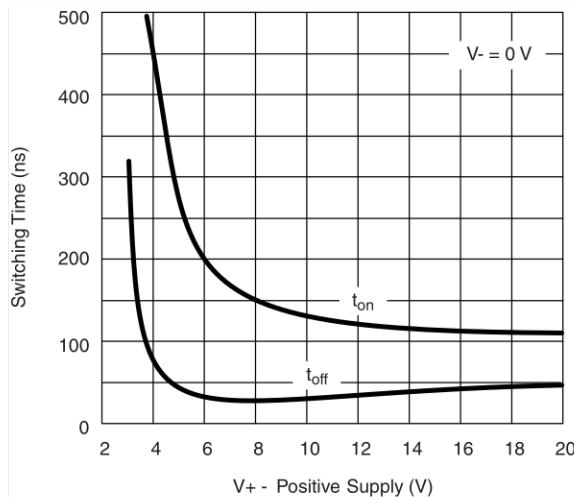
Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

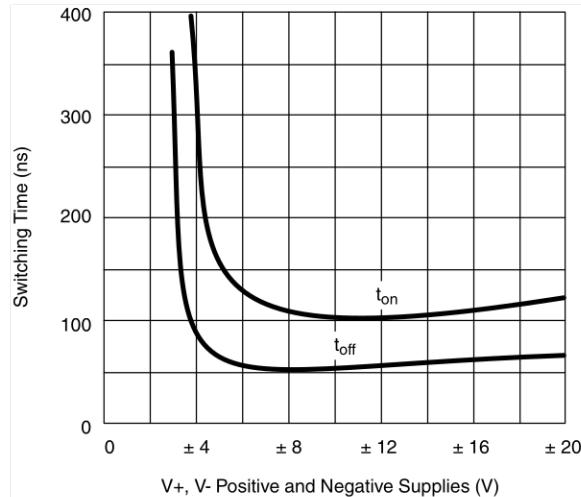
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)


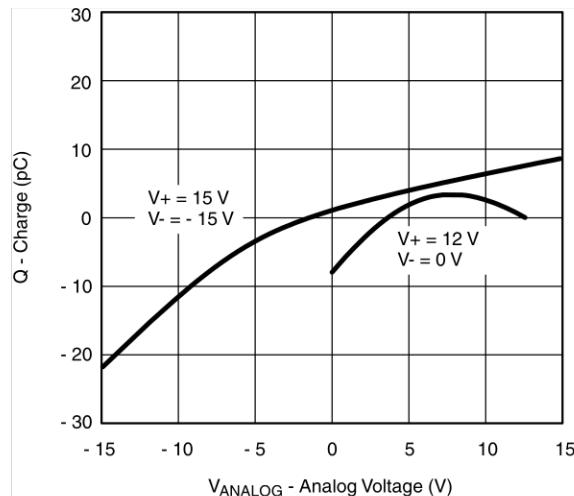
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



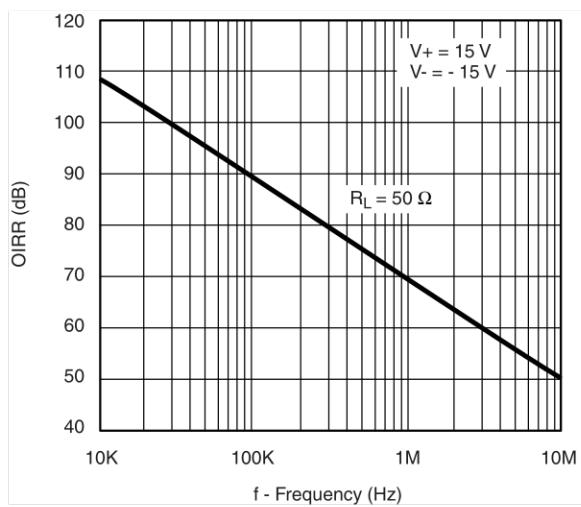
Switching Time vs. Single Supply Voltage



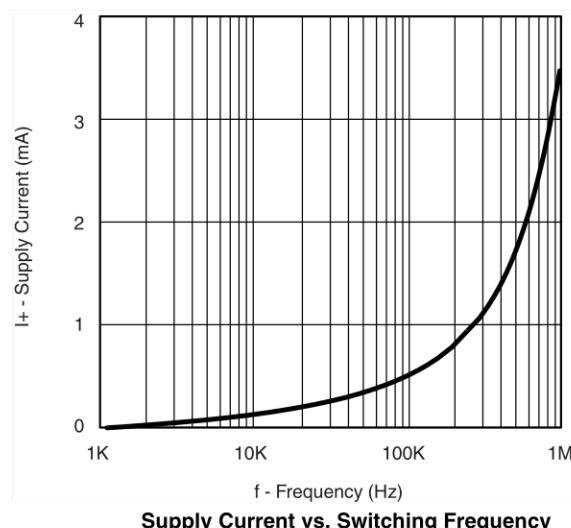
Switching Time vs. Power Supply Voltage



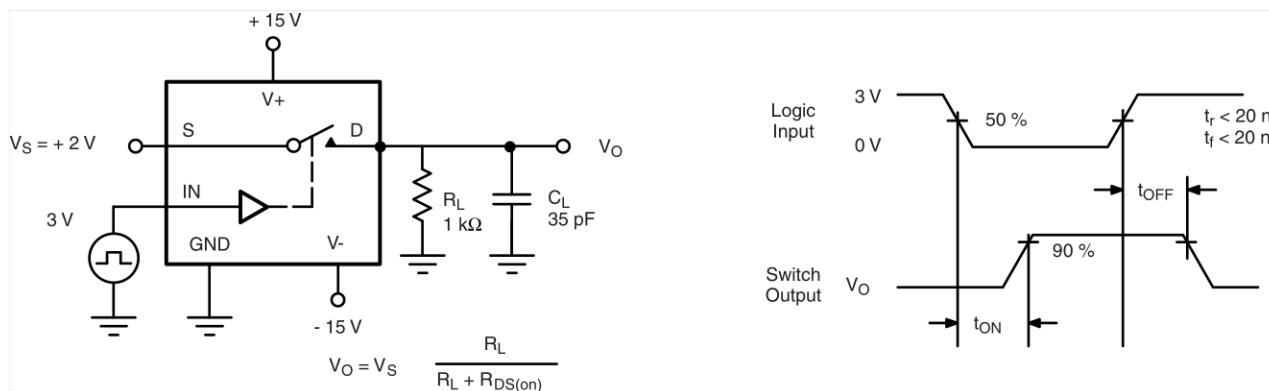
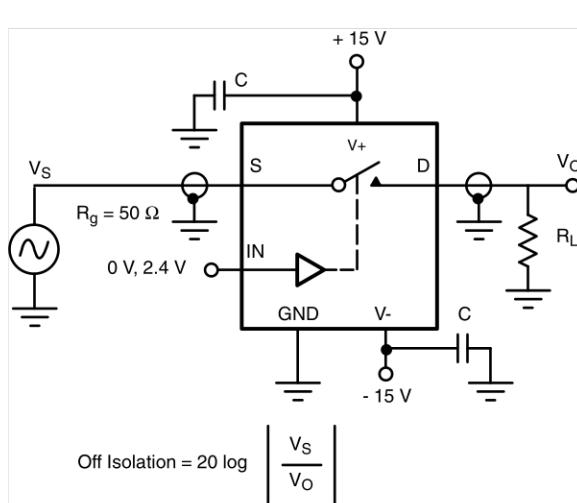
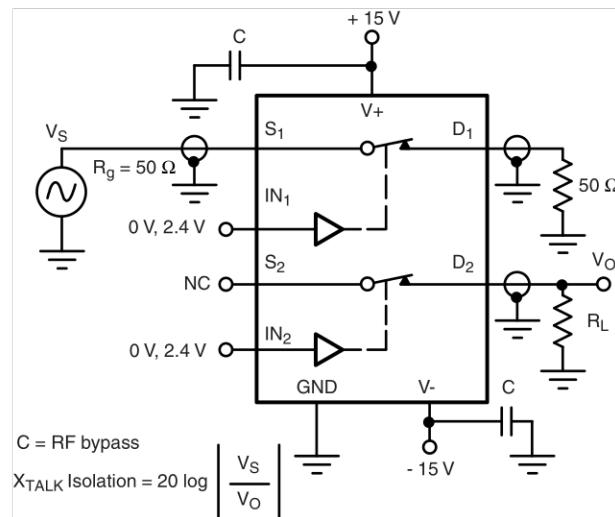
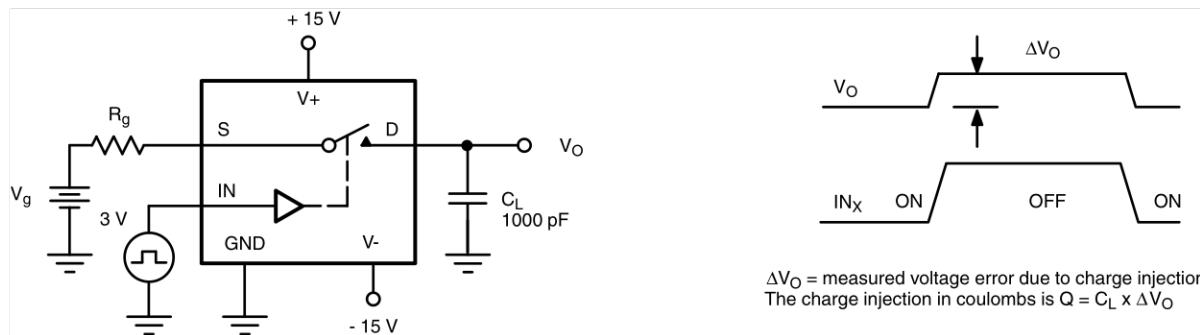
Q_S , Q_D - Charge Injection vs. Analog Voltage



Off Isolation vs. Frequency



Supply Current vs. Switching Frequency

TEST CIRCUITS

Figure 2. Switching Time

Figure 3. Off Isolation

Figure 4. Channel-to-Channel Crosstalk

Figure 5. Charge Injection

DG201B, DG202B

Vishay Siliconix



APPLICATIONS

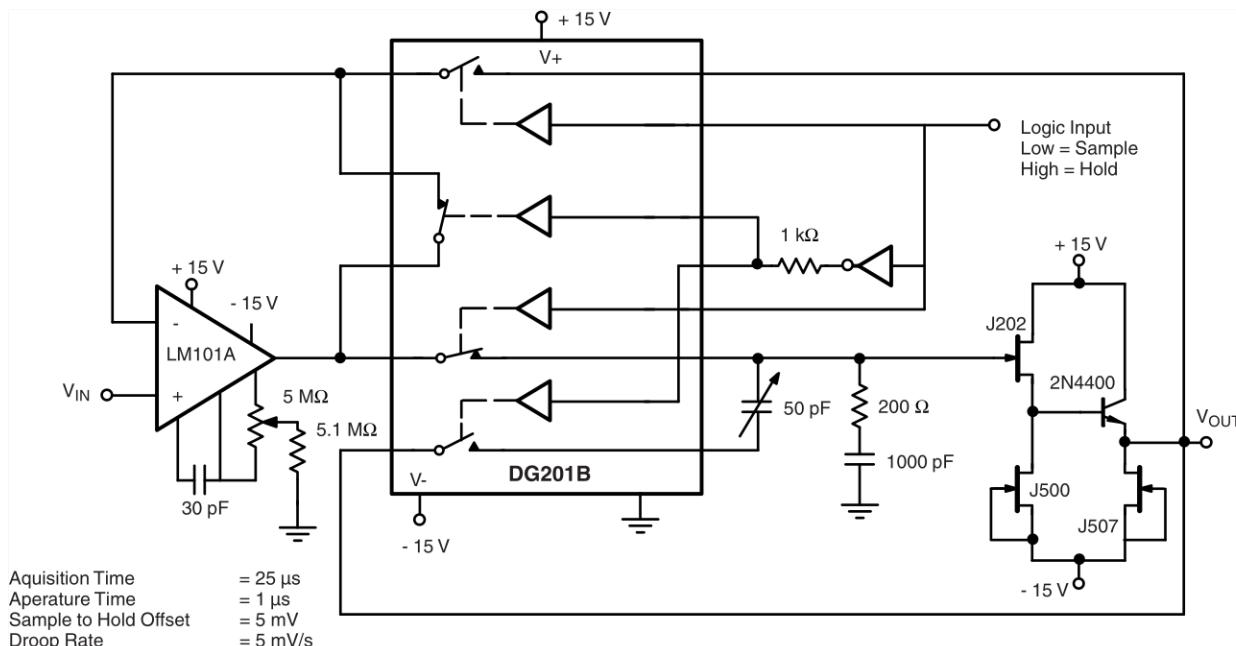


Figure 6. Sample-and-Hold

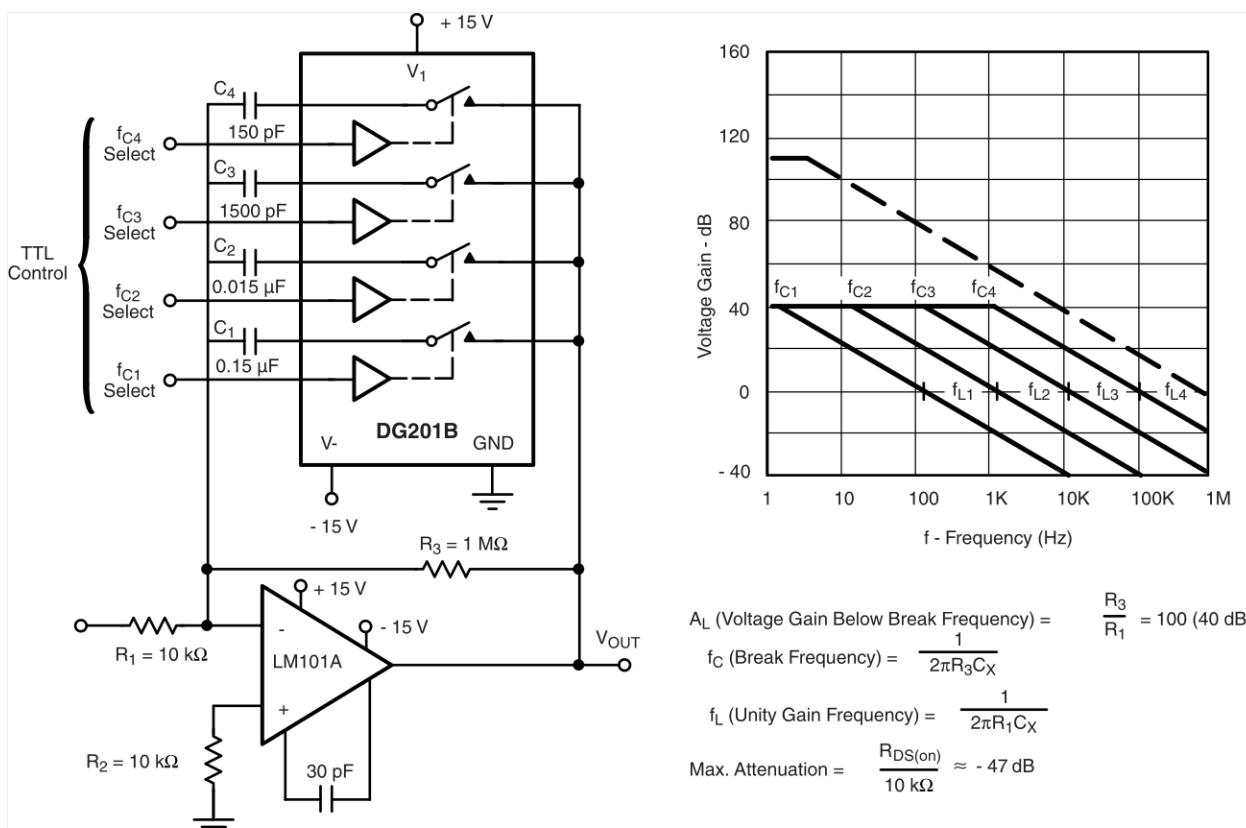


Figure 7. Active Low Pass Filter with Digitally Selected Break Frequency

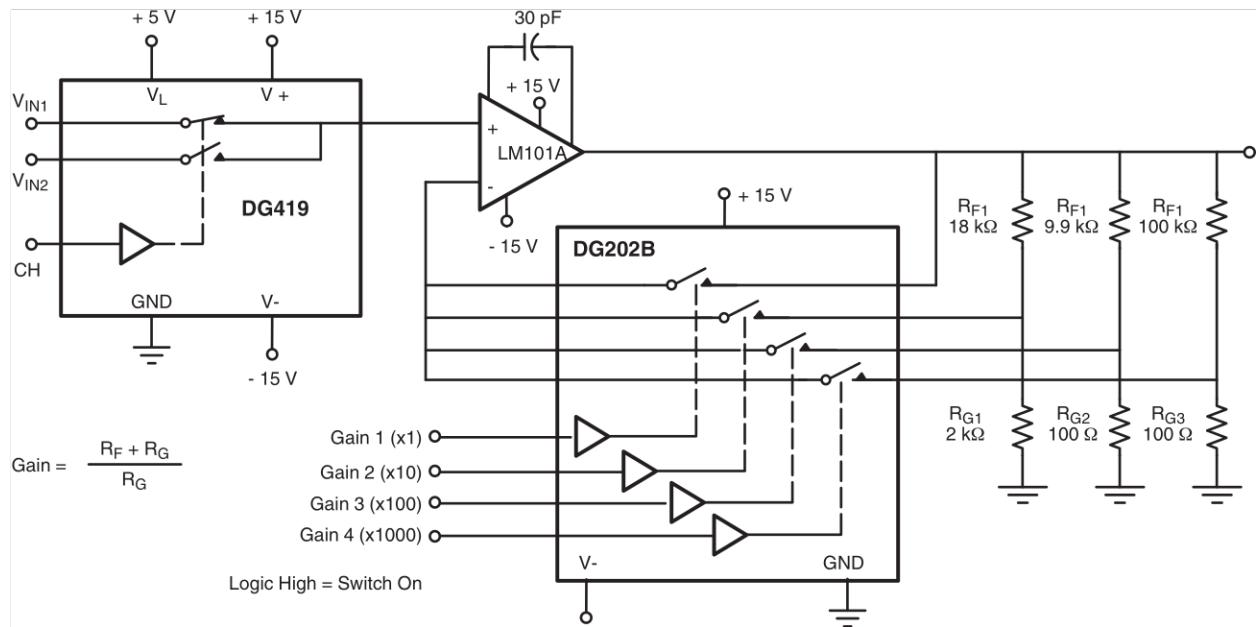
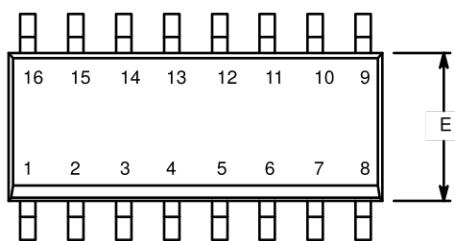
APPLICATIONS


Figure 8. A Precision Amplifier with Digitally Programmable Input and Gains

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70037.

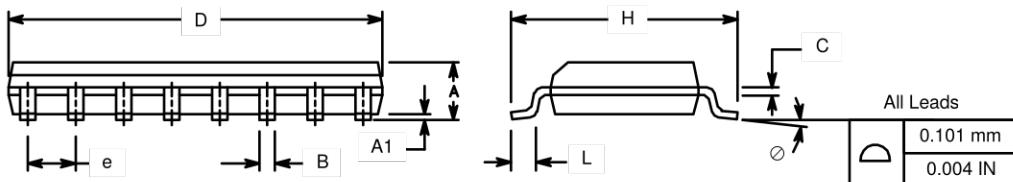
SOIC (NARROW): 16-LEAD

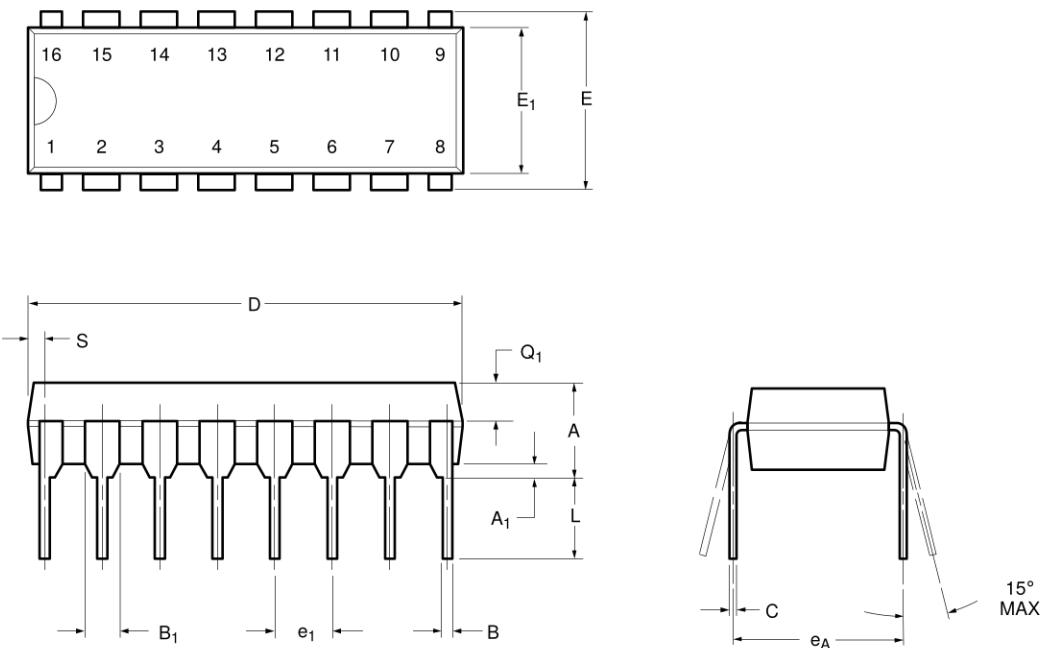
JEDEC Part Number: MS-012



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
\emptyset	0°	8°	0°	8°

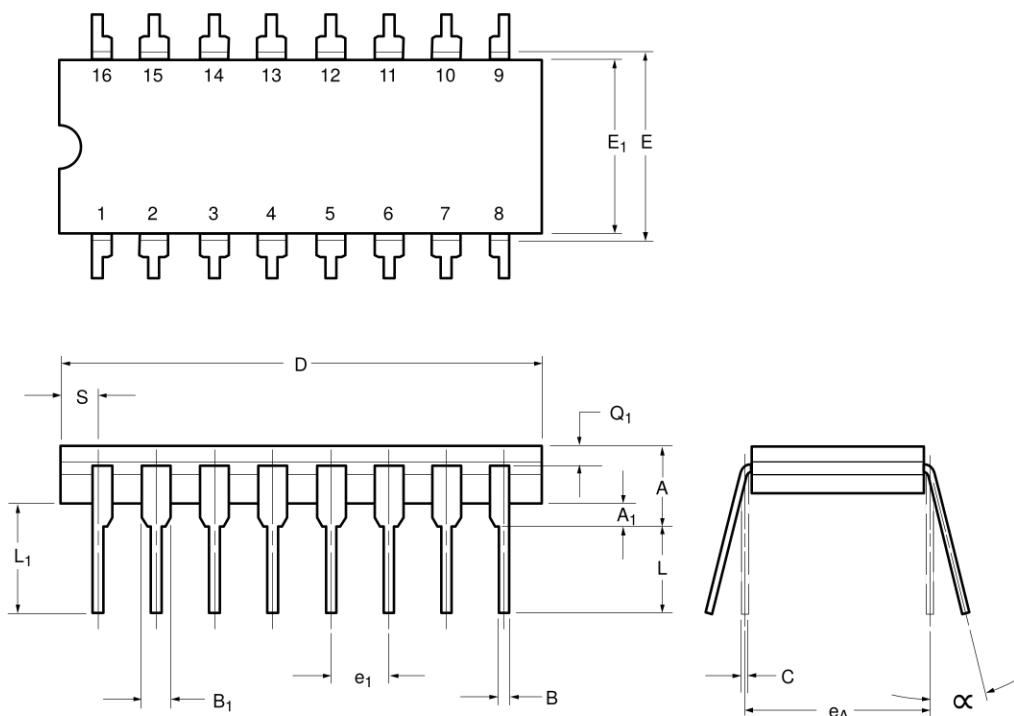
ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



PDIP: 16-LEAD


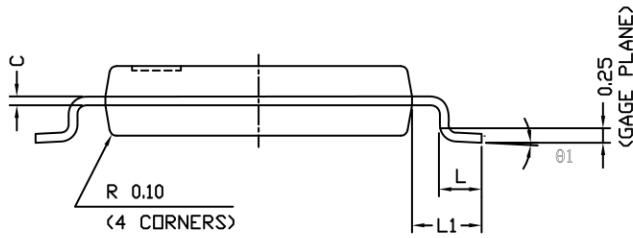
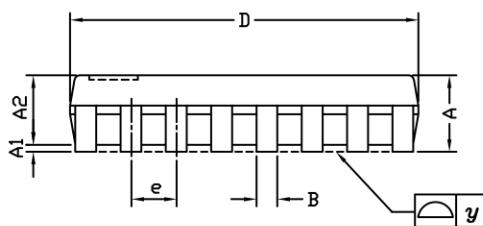
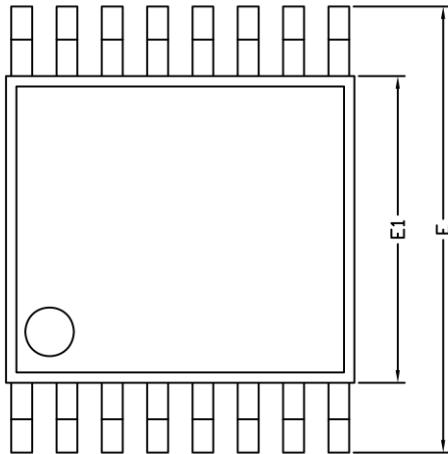
Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E₁	5.59	7.11	0.220	0.280
e₁	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

CERDIP: 16-LEAD


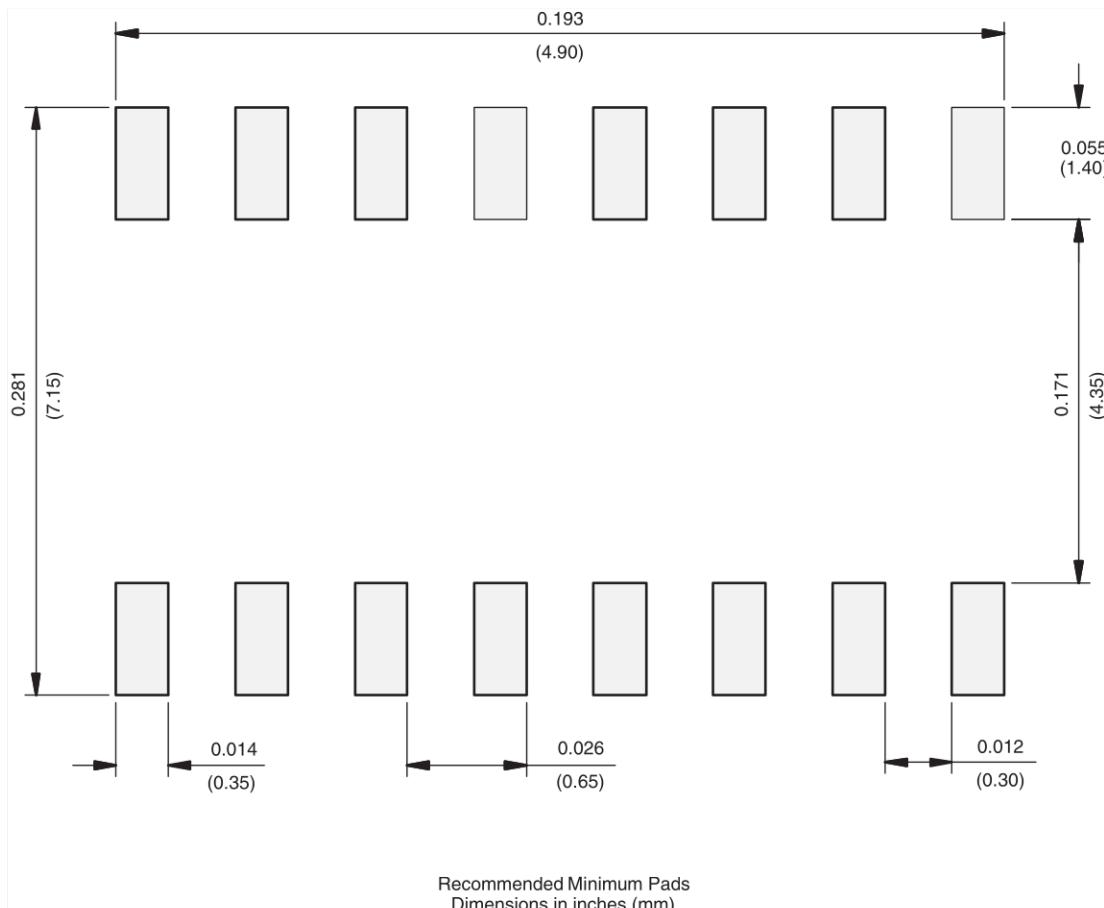
Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	4.06	5.08	0.160	0.200
A₁	0.51	1.14	0.020	0.045
B	0.38	0.51	0.015	0.020
B₁	1.14	1.65	0.045	0.065
C	0.20	0.30	0.008	0.012
D	19.05	19.56	0.750	0.770
E	7.62	8.26	0.300	0.325
E₁	6.60	7.62	0.260	0.300
e₁	2.54 BSC		0.100 BSC	
e_A	7.62 BSC		0.300 BSC	
L	3.18	3.81	0.125	0.150
L₁	3.81	5.08	0.150	0.200
Q₁	1.27	2.16	0.050	0.085
S	0.38	1.14	0.015	0.045
α	0°	15°	0°	15°
ECN: S-03946—Rev. G, 09-Jul-01				
DWG: 5403				

TSSOP: 16-LEAD

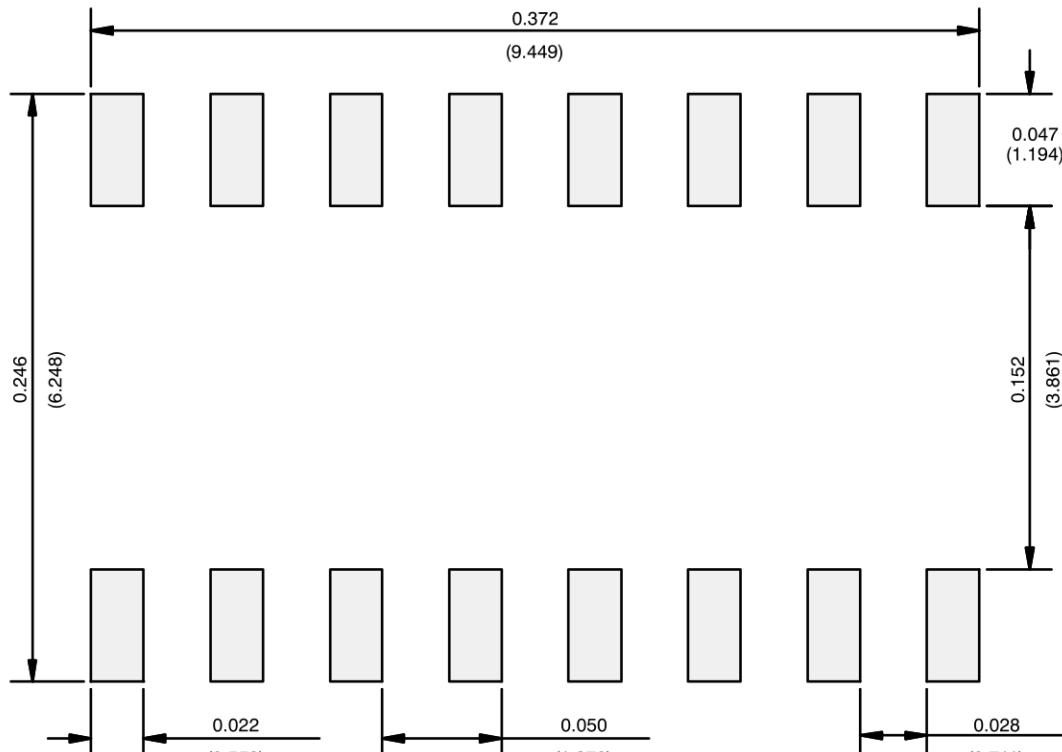


Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°

ECN: S-61920-Rev. D, 23-Oct-06
DWG: 5624

RECOMMENDED MINIMUM PAD FOR TSSOP-16

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.